TOSHIBA Intelligent Power Module Silicon N Channel IGBT

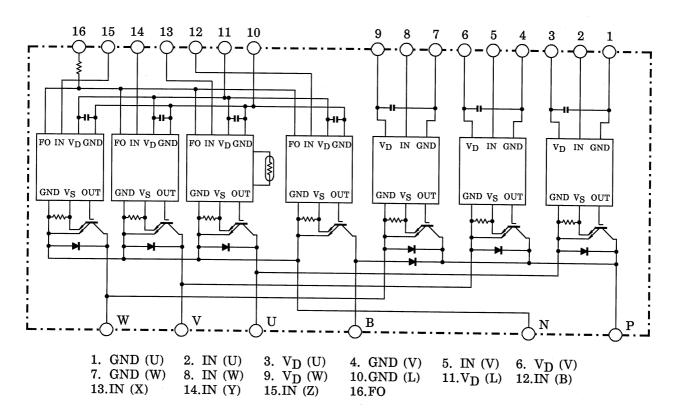
MIG100Q201H

High Power Switching Applications

Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : V_{CE} (sat) = 3.5 V (Max.)
 - $t_{off} = 2.5 \ \mu s \ (Max.)$
 - $t_{rr} = 0.21 \ \mu s$ (Max.)
- Outline : TOSHIBA 2-136A1A
- Weight :

Equivalent Circuit



Maximum Ratings (T_j = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	_	V _{CES}	1200	V
	Collector current	T _c = 25°C, DC	Ι _C	100	А
Inventer	Forward current	T _c = 25°C, DC	١ _F	100	А
	Collector power dissipation	T _c = 25°C	P _C	800	W
	Junction temperature	—	Tj	150	°C
Brake	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	—	V _{CES}	1200	V
	Collector current	T _c = 25°C, DC	Ι _C	50	А
	Reverse voltage	—	V _R	1200	V
	Forward current	T _c = 25°C, DC	١ _F	50	А
	Collector power dissipation	T _c = 25°C	P _C	400	W
	Junction temperature	—	Tj	150	°C
Control	Control supply voltage	V _D -GND terminal	VD	20	V
	Input voltage	IN-GND terminal	V _{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
Module	Operating temperature	—	TC	-20 ~ +100	°C
	Storage temperature range	—	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5	—	3	N∙m

Electrical Characteristics ($T_j = 25^{\circ}C$)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 1200 V	T _j = 25°C	_	_	1	mA
			T _j = 125°C	_	_	20	IIIA
Collector-emitter saturation	V _{CE (sat)}	V_D = 15 V, I _C = 100 A V_{IN} = 3 V \rightarrow 0 V	T _j = 25°C	_	2.7	3.5	v
voltage			T _j = 125°C	_	2.6	_	
Forward voltage	V _F	I _F = 100 A		_	2.0	2.7	V
	t _{on}	V_{CC} = 600 V, I_C = 100 A V_D = 15 V, V_{IN} = 3 V ↔ 0 V Inductive load		0.8	1.5	2.2	μs
	t _{o(on)}			_	0.5	1.0	
Switching time	t _{rr}			_	0.14	0.21	
	t _{off}		(Note 1)	_	1.5	2.5	
	t _{c(off)}			_	0.3	0.6	

b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 1200V	T _j = 25°C	_	—	1	mA
			T _j = 125°C	_	—	20	IIIA
Collector-emitter saturation voltage	V _{CE (sat)}	V _D = 15V, I _C = 50A V _{IN} = 3V→0V	T _j = 25°C	—	2.7	3.5	v
			T _j = 125°C	_	2.6	_	
Reverse current	۱ _R	V _R = 1200V	T _j = 25°C	_	—	1	mA
Reverse current			T _j = 125°C	_	—	20	
Forward voltage	VF	I _F = 50A		_	2.0	2.7	V
	t _{on}	$V_{CC} = 600V, I_C = 50A$ $V_D = 15V, V_{IN} = 3V \leftrightarrow 0V$ Inductive load		0.8	1.5	2.2	-
	t _{c(on)}			_	0.5	1.0	
Switching time	t _{rr}			_	0.30	0.45	μs
	t _{off}]	(Note 1)	_	1.5	2.5	
	t _{c(off)}]		—	0.3	0.6	

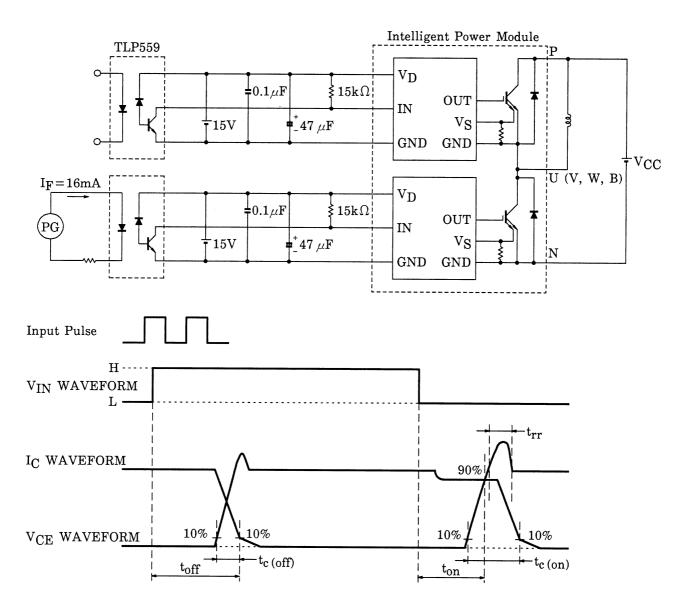
c. Control Stage ($T_j = 25^{\circ}C$)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	— V _D = 15 V	_	20	30	mA
	Low side	I _{D (L)}		—	80	120	
Input-on signal voltage		V _{IN (on)}	V _D = 15 V, I _C = 100 mA	0.9	1.1	1.3	V
Fault output current	Protection	I _{FO (on)}	— V _D = 15 V	8	10	12	mA
	Normal	I _{FO (off)}		—	_	1	
Over current protection trip level	Inverter		C V _D = 15 V, T _j = 125°C	160	200	—	A
	Brake	OC		70	100	_	
Short current protection trip level	Inverter		V _D = 15 V, T _j = 125°C	240	300	—	A
	Brake	SC		105	150	_	
Over current cut-off time		t _{off (OC)}	V _D = 15 V	_	10	_	μs
Over temperature protection	Trip level	ОТ	Case temperature	111	118	125	°C
	Reset level	OTr		93	100	107	
Control supply under voltage protection	Trip level	UV		11.3	12.0	12.7	
	Reset level	UVr	-	11.8	12.5	13.2	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

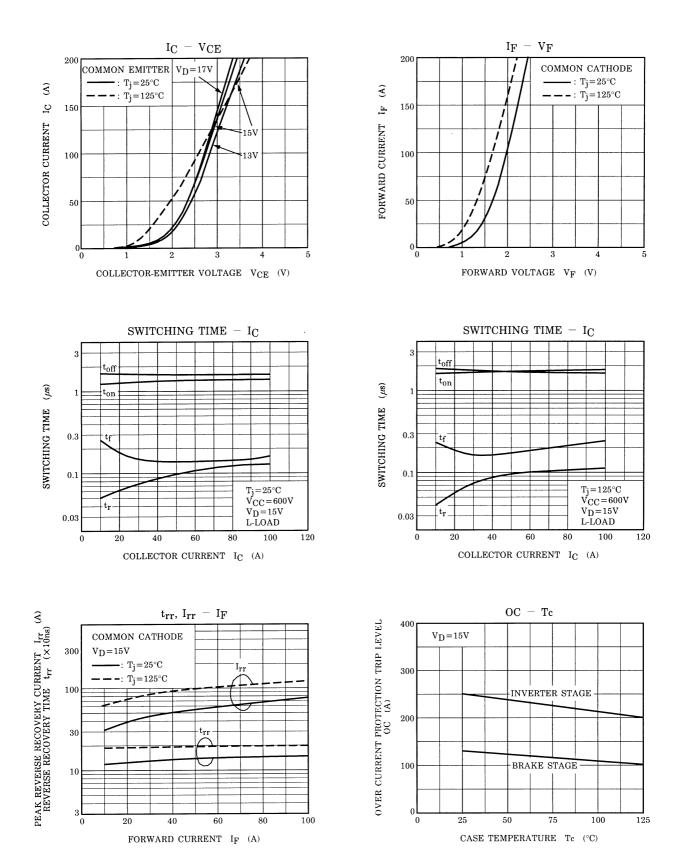
d. Thermal Resistance (T_j = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Junction to case thermal resistance	R _{th (j-c)}	Inverter IGBT	_	_	0.156	°C / W
		Inverter FRD	_	-	0.50	
		Brake IGBT	_		0.312	
		Brake FRD	-	_	1.00	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied		0.04	_	°C/W

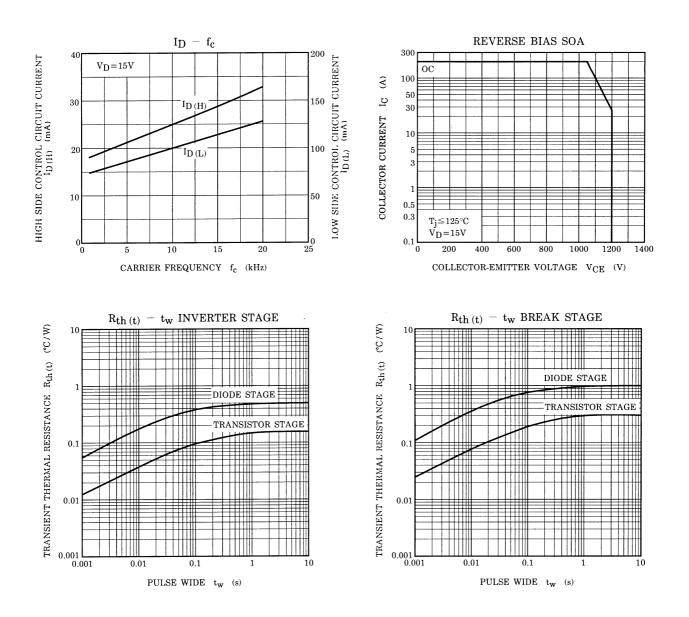
Note 1 : Switching time test circuit & timing chart



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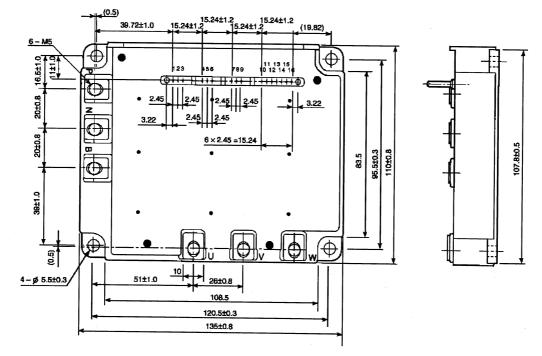


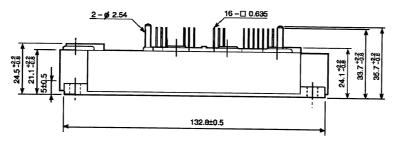
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Package Dimensions: TOSHIBA 2-136A1A

Unit: mm





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